

# MC74LVX245

## Octal Bus Transceiver

### With 5 V-Tolerant Inputs

The MC74LVX245 is an advanced high speed CMOS octal bus transceiver.

It is intended for two-way asynchronous communication between data buses. The direction of data transmission is determined by the level of the T/R input. The output enable pin ( $\overline{OE}$ ) can be used to disable the device, so that the buses are effectively isolated.

All inputs are equipped with protection circuits against static discharge.

#### Features

- High Speed:  $t_{PD} = 4.7$  ns (Typ) at  $V_{CC} = 3.3$  V
- Low Power Dissipation:  $I_{CC} = 4$   $\mu$ A (Max) at  $T_A = 25^\circ$ C
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Low Noise:  $V_{OLP} = 0.8$  V (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance: Human Body Model > 2000 V;  
Machine Model > 200 V
- These Devices are Pb-Free and are RoHS Compliant

#### Application Notes

- Do Not Force a Signal on an I/O Pin when it is an Active Output, Damage May Occur
- All Floating (High Impedance) Input or I/O Pins must be Fixed by Means of Pullup or Pulldown Resistors or Bus Terminator ICs
- A Parasitic Diode is Formed between the Bus and  $V_{CC}$  Terminals Therefore, the LVX245 cannot be Used to Interface 5.0 V to 3.0 V Systems Directly



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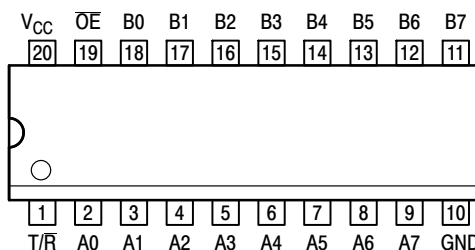


**SOIC-20**  
**DW SUFFIX**  
**CASE 751D**



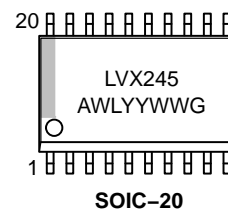
**TSSOP-20**  
**DT SUFFIX**  
**CASE 948E**

#### PIN ASSIGNMENT

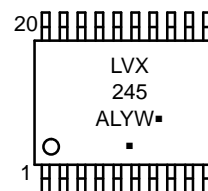


**20-Lead (Top View)**

#### MARKING DIAGRAMS



**SOIC-20**



**TSSOP-20**

LVX245 = Specific Device Code  
A = Assembly Location  
WL, L = Wafer Lot  
Y = Year  
WW, W = Work Week  
G or  $\blacksquare$  = Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# MC74LVX245

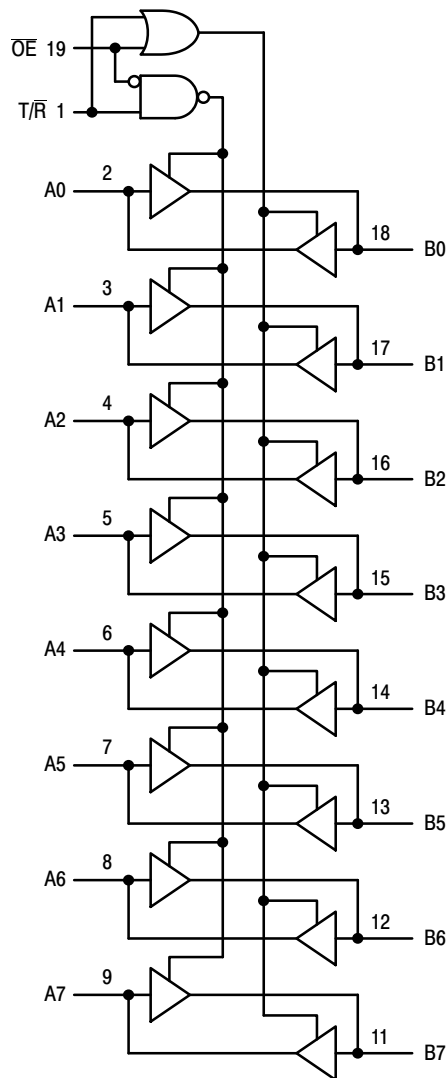


Figure 1. Logic Diagram

Table 1. PIN NAMES

| Pins  | Function                                 |
|-------|--|
| OE    | Output Enable Input                      |
| T/R   | Transmit/Receive Input                   |
| A0–A7 | Side A 3–State Inputs or 3–State Outputs |
| Bo–B7 | Side B 3–State Inputs or 3–State Outputs |

| INPUTS |     | OPERATING MODE<br>Non-Inverting |
|--------|-----|---------------------------------|
| OE     | T/R |                                 |
| L      | L   | B Data to A Bus                 |
| L      | H   | A Data to B Bus                 |
| H      | X   | Z                               |

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State;  
X = High or Low Voltage Level and Transitions are Acceptable; For  $I_{CC}$   
reasons, Do Not Float Inputs

# MC74LVX245

## MAXIMUM RATINGS

| Symbol           | Parameter                                       | Value                        | Unit |
|------------------|---|------------------------------|------|
| V <sub>CC</sub>  | DC Supply Voltage                               | −0.5 to +7.0                 | V    |
| V <sub>in</sub>  | DC Input Voltage (T/R, OE)                      | −0.5 to +7.0                 | V    |
| V <sub>I/O</sub> | DC Output Voltage                               | −0.5 to V <sub>CC</sub> +0.5 | V    |
| I <sub>IK</sub>  | Input Diode Current                             | −20                          | mA   |
| I <sub>OK</sub>  | Output Diode Current                            | ±20                          | mA   |
| I <sub>out</sub> | DC Output Current, per Pin                      | ±25                          | mA   |
| I <sub>CC</sub>  | DC Supply Current, V <sub>CC</sub> and GND Pins | ±75                          | mA   |
| P <sub>D</sub>   | Power Dissipation                               | 180                          | mW   |
| T <sub>stg</sub> | Storage Temperature                             | −65 to +150                  | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## RECOMMENDED OPERATING CONDITIONS

| Symbol           | Parameter                                | Min | Max             | Unit |
|------------------|--|-----|-----------------|------|
| V <sub>CC</sub>  | DC Supply Voltage                        | 2.0 | 3.6             | V    |
| V <sub>in</sub>  | DC Input Voltage (T/R, OE)               | 0   | 5.5             | V    |
| V <sub>I/O</sub> | DC Output Voltage                        | 0   | V <sub>CC</sub> | V    |
| T <sub>A</sub>   | Operating Temperature, All Package Types | −40 | +85             | °C   |
| Δt/ΔV            | Input Rise and Fall Time                 | 0   | 100             | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

## DC ELECTRICAL CHARACTERISTICS

| Symbol          | Parameter  | Test Conditions   | V <sub>CC</sub><br>V | T <sub>A</sub> = 25°C |            |                    | T <sub>A</sub> = −40 to 85°C |                    | Unit |
|-----------------|--|---|----------------------|-----------------------|------------|--------------------|------------------------------|--------------------|------|
|                 |  |   |                      | Min                   | Typ        | Max                | Min                          | Max                |      |
| V <sub>IH</sub> | High-Level Input Voltage   |   | 2.0<br>3.0<br>3.6    | 1.5<br>2.0<br>2.4     |            |                    | 1.5<br>2.0<br>2.4            |                    | V    |
| V <sub>IL</sub> | Low-Level Input Voltage  |   | 2.0<br>3.0<br>3.6    |                       |            | 0.5<br>0.8<br>0.8  |                              | 0.5<br>0.8<br>0.8  | V    |
| V <sub>OH</sub> | High-Level Output Voltage<br>(V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub> ) | I <sub>OH</sub> = −50 μA<br>I <sub>OH</sub> = −50 μA<br>I <sub>OH</sub> = −4 mA                   | 2.0<br>3.0<br>3.0    | 1.9<br>2.9<br>2.58    | 2.0<br>3.0 |                    | 1.9<br>2.9<br>2.48           |                    | V    |
| V <sub>OL</sub> | Low-Level Output Voltage<br>(V <sub>in</sub> = V <sub>IH</sub> or V <sub>IL</sub> )  | I <sub>OL</sub> = 50 μA<br>I <sub>OL</sub> = 50 μA<br>I <sub>OL</sub> = 4 mA                      | 2.0<br>3.0<br>3.0    |                       | 0.0<br>0.0 | 0.1<br>0.1<br>0.36 |                              | 0.1<br>0.1<br>0.44 | V    |
| I <sub>in</sub> | Input Leakage Current  | V <sub>in</sub> = 5.5 V or GND<br>(T/R, OE)   | 3.6                  |                       |            | ±0.1               |                              | ±1.0               | μA   |
| I <sub>OZ</sub> | Maximum 3-State Leakage Current  | V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub><br>V <sub>out</sub> = V <sub>CC</sub> or GND | 3.6                  |                       |            | ±0.2<br>5          |                              | ±2.5               | μA   |
| I <sub>CC</sub> | Quiescent Supply Current   | V <sub>in</sub> = V <sub>CC</sub> or GND  | 3.6                  |                       |            | 4.0                |                              | 40.0               | μA   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# MC74LVX245

## AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns)

| Symbol                     | Parameter                                      | Test Conditions  | $T_A = 25^\circ\text{C}$ |             |              | $T_A = -40$ to $85^\circ\text{C}$ |              | Unit |
|----------------------------|--|--|--------------------------|-------------|--------------|-----------------------------------|--------------|------|
|                            |  |  | Min                      | Typ         | Max          | Min                               | Max          |      |
| $t_{PLH}$ ,<br>$t_{PHL}$   | Propagation Delay<br>Input to Output           | $V_{CC} = 2.7$ V $C_L = 15$ pF<br>$C_L = 50$ pF                              |                          | 6.1<br>8.6  | 10.7<br>14.2 | 1.0<br>1.0                        | 13.5<br>17.0 | ns   |
|                            |  | $V_{CC} = 3.3 \pm 0.3$ V $C_L = 15$ pF<br>$C_L = 50$ pF                      |                          | 4.7<br>7.2  | 6.6<br>10.1  | 1.0<br>1.0                        | 8.0<br>11.5  |      |
| $t_{PZL}$ ,<br>$t_{PZH}$   | Output Enable Time to<br>High and Low Level    | $V_{CC} = 2.7$ V $C_L = 15$ pF<br>$R_L = 1$ k $\Omega$ $C_L = 50$ pF         |                          | 9.0<br>11.5 | 16.9<br>20.4 | 1.0<br>1.0                        | 20.5<br>24.0 | ns   |
|                            |  | $V_{CC} = 3.3 \pm 0.3$ V $C_L = 15$ pF<br>$R_L = 1$ k $\Omega$ $C_L = 50$ pF |                          | 7.1<br>9.6  | 11.0<br>14.5 | 1.0<br>1.0                        | 13.0<br>16.5 |      |
| $t_{PLZ}$ ,<br>$t_{PHZ}$   | Output Disable Time From<br>High and Low Level | $V_{CC} = 2.7$ V $C_L = 50$ pF<br>$R_L = 1$ k $\Omega$                       |                          | 11.5        | 18.0         | 1.0                               | 21.0         | ns   |
|                            |  | $V_{CC} = 3.3 \pm 0.3$ V $C_L = 50$ pF<br>$R_L = 1$ k $\Omega$               |                          | 9.6         | 12.8         | 1.0                               | 14.5         |      |
| $t_{OSHL}$ ,<br>$t_{OSLH}$ | Output-to-Output Skew<br>(Note 1)              | $V_{CC} = 2.7$ V $C_L = 50$ pF<br>$V_{CC} = 3.3 \pm 0.3$ V $C_L = 50$ pF     |                          |             | 1.5<br>1.5   |                                   | 1.5<br>1.5   | ns   |

1. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW ( $t_{OSHL}$ ) or LOW-to-HIGH ( $t_{OSLH}$ ); parameter guaranteed by design.

## CAPACITIVE CHARACTERISTICS

| Symbol    | Parameter                              | $T_A = 25^\circ\text{C}$ |     |     | $T_A = -40$ to $85^\circ\text{C}$ |     | Unit |
|-----------|--|--------------------------|-----|-----|-----------------------------------|-----|------|
|           |  | Min                      | Typ | Max | Min                               | Max |      |
| $C_{in}$  | Input Capacitance (T/R, OE)            |                          | 4   | 10  |                                   | 10  | pF   |
| $C_{I/O}$ | Maximum 3-State I/O Capacitance        |                          | 8   |     |                                   |     | pF   |
| $C_{PD}$  | Power Dissipation Capacitance (Note 2) |                          | 21  |     |                                   |     | pF   |

2.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \cdot V_{CC} \cdot f_{in} + I_{CC}/8$  (per bit).  $C_{PD}$  is used to determine the no-load dynamic power consumption;  $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_{in} + I_{CC} \cdot V_{CC}$ .

## NOISE CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns, $C_L = 50$ pF, $V_{CC} = 3.3$ V, Measured in SOIC Package)

| Symbol    | Characteristic                           | $T_A = 25^\circ\text{C}$ |      | Unit |
|-----------|--|--------------------------|------|------|
|           |  | Typ                      | Max  |      |
| $V_{OLP}$ | Quiet Output Maximum Dynamic $V_{OL}$    | 0.5                      | 0.8  | V    |
| $V_{OLV}$ | Quiet Output Minimum Dynamic $V_{OL}$    | -0.5                     | -0.8 | V    |
| $V_{IHD}$ | Minimum High Level Dynamic Input Voltage |                          | 2.0  | V    |
| $V_{ILD}$ | Maximum Low Level Dynamic Input Voltage  |                          | 0.8  | V    |

# MC74LVX245

## SWITCHING WAVEFORMS

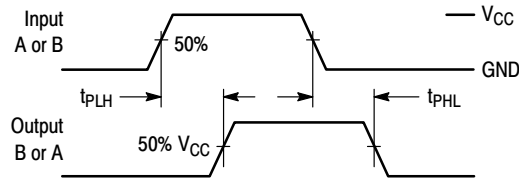


Figure 2.

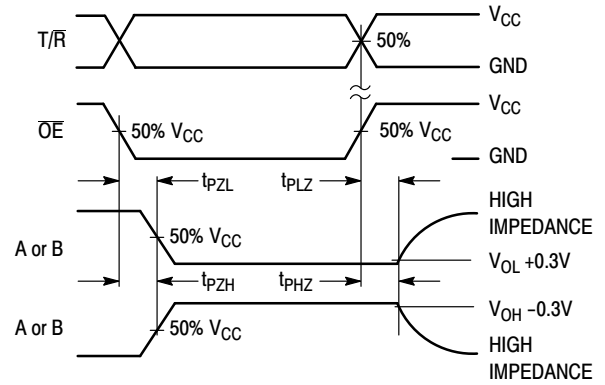
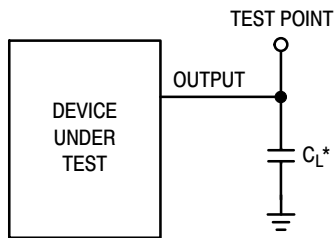


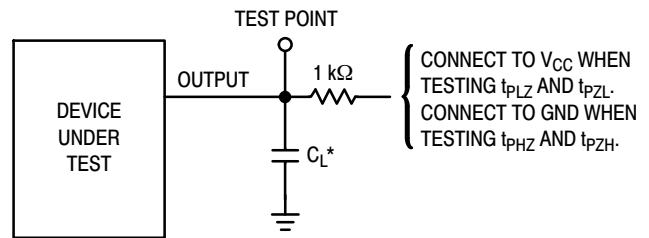
Figure 3.

## TEST CIRCUITS



\*Includes all probe and jig capacitance

Figure 4. Propagation Delay Test Circuit



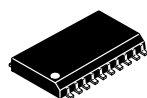
\*Includes all probe and jig capacitance

Figure 5. 3-State Test Circuit

## ORDERING INFORMATION

| Device          | Package            | Shipping <sup>†</sup> |
|-----------------|--------------------|-----------------------|
| MC74LVX245DWR2G | SOIC-20 (Pb-Free)  | 1000 / Tape & Reel    |
| MC74LVX245DTR2G | TSSOP-20 (Pb-Free) | 2500 / Tape & Reel    |

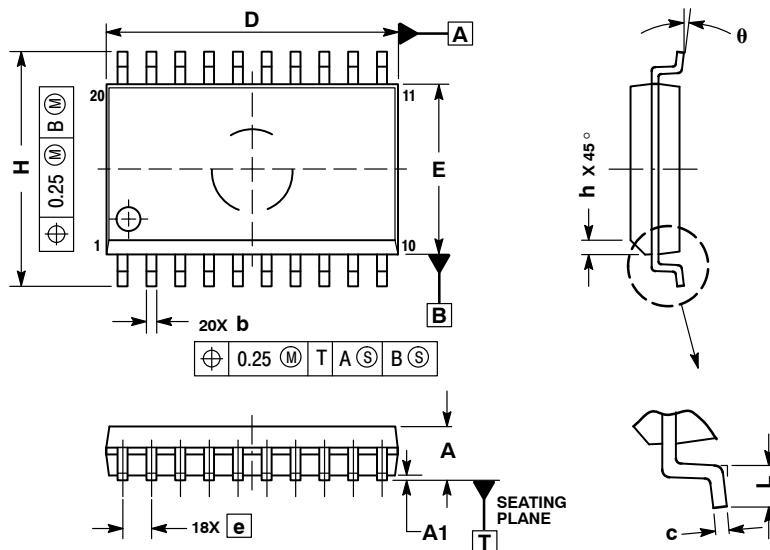
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



SCALE 1:1

### SOIC-20 WB CASE 751D-05 ISSUE H

DATE 22 APR 2015

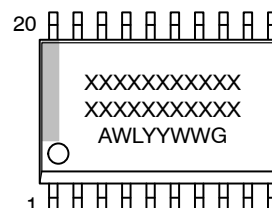


#### NOTES:

1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

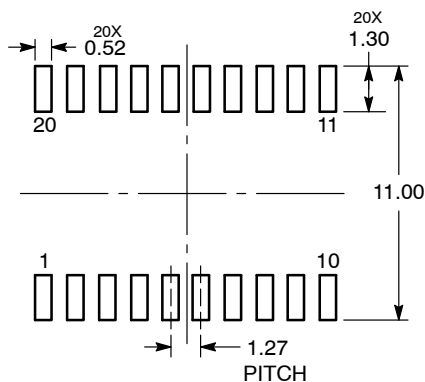
| DIM | MILLIMETERS |       |
|-----|-------------|-------|
|     | MIN         | MAX   |
| A   | 2.35        | 2.65  |
| A1  | 0.10        | 0.25  |
| b   | 0.35        | 0.49  |
| c   | 0.23        | 0.32  |
| D   | 12.65       | 12.95 |
| E   | 7.40        | 7.60  |
| e   | 1.27 BSC    |       |
| H   | 10.05       | 10.55 |
| h   | 0.25        | 0.75  |
| L   | 0.50        | 0.90  |
| θ   | 0°          | 7°    |

### GENERIC MARKING DIAGRAM\*



XXXXXX = Specific Device Code  
A = Assembly Location  
WL = Wafer Lot  
YY = Year  
WW = Work Week  
G = Pb-Free Package

### RECOMMENDED SOLDERING FOOTPRINT\*



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

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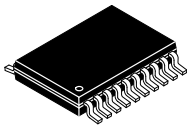
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# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

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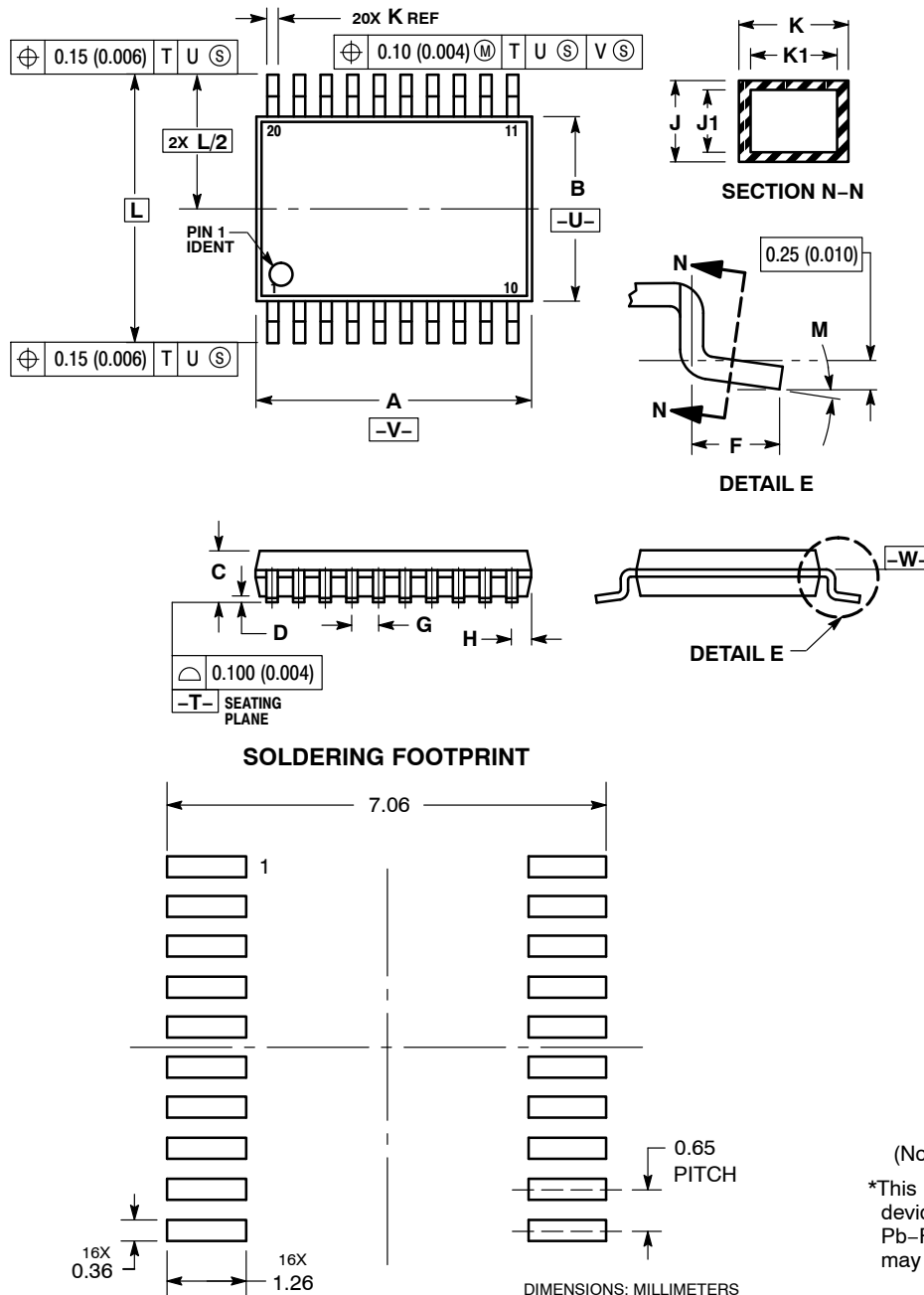
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SCALE 2:1

TSSOP-20 WB  
CASE 948E  
ISSUE D

DATE 17 FEB 2016

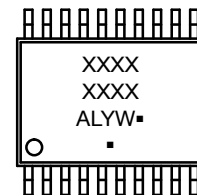


### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 6.40        | 6.60 | 0.252     | 0.260 |
| B   | 4.30        | 4.50 | 0.169     | 0.177 |
| C   | ---         | 1.20 | ---       | 0.047 |
| D   | 0.05        | 0.15 | 0.002     | 0.006 |
| F   | 0.50        | 0.75 | 0.020     | 0.030 |
| G   | 0.65 BSC    |      | 0.026 BSC |       |
| H   | 0.27        | 0.37 | 0.011     | 0.015 |
| J   | 0.09        | 0.20 | 0.004     | 0.008 |
| J1  | 0.09        | 0.16 | 0.004     | 0.006 |
| K   | 0.19        | 0.30 | 0.007     | 0.012 |
| K1  | 0.19        | 0.25 | 0.007     | 0.010 |
| L   | 6.40 BSC    |      | 0.252 BSC |       |
| M   | 0°          | 8°   | 0°        | 8°    |

### GENERIC MARKING DIAGRAM\*




- A = Assembly Location
- L = Wafer Lot
- Y = Year
- W = Work Week
- = Pb-Free Package

(Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

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